

Product Summary

- Continuous Drain-Source Voltage: V_{DS} = 60V
- On-State Resistance: 500mΩ
- Max Nominal Load Current (VIN = 5V): 1.1A
- Min Nominal Load Current (VIN = 5V): 0.7A
- Clamping Energy: 550mJ

Description

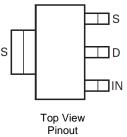
The BSP75NQ is a self-protected low-side IntelliFET[®] MOSFET. It features monolithic overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic-level functionality. It is intended as a general-purpose switch.

Applications

- Especially suited for loads with a high inrush current such as lamps and motors
- All types of resistive, inductive and capacitive loads in switching applications
- µC compatible power switches for 12V and 24V DC applications
- Automotive rated
- Replaces electromechanical relays and discrete circuits
- Linear mode capabilities the current-limiting protection circuitry is designed to de-activate at low V_{DS} in order not to compromise the load current during normal operation. The maximum DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low V_{DS}.

SOT223 (Type DN)





Note: The tab is connected to the source pin and must be electrically isolated from the drain pin. Connection of significant copper to the drain pin is recommended for best thermal performance.

Ordering Information (Note 4)

Orderable Part Number	Baakaga	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Orderable Fait Number	Package	ackage warking Reel Size (inches) Tape width (ini	rape width (mm)	Qty.	Carrier	
BSP75NQTA	SOT223 (Type DN)	BSP75N	7	12	1,000 Units	Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

BSP75NQ Document number: DS37145 Rev. 8 - 2

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Features and Benefits

- Short-Circuit Protection with Auto Restart
- Overvoltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Overcurrent Protection
- Input Protection (ESD)
- Load Dump Protection (Actively Protects Load)
- Logic-Level Input
- High Continuous Current Rating
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BSP75NQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

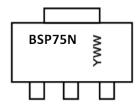
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (3)
- Weight: 0.112 grams (Approximate)

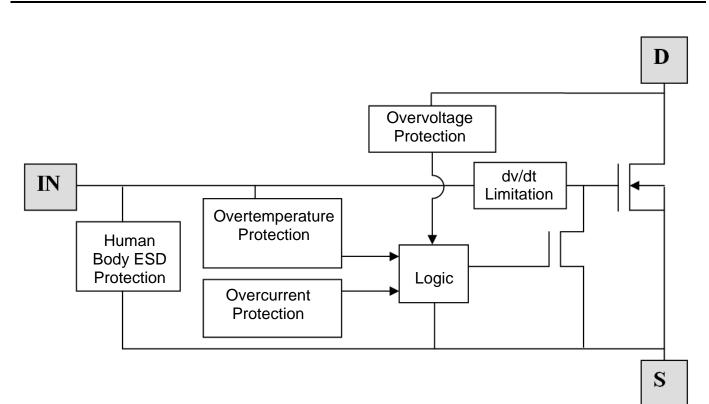


Marking Information



 $\begin{array}{l} BSP75N = Product Type Marking Code \\ YWW = Date Code Marking \\ Y \ or \ \overline{Y} = Last Digit \ of \ Year \ (ex: \ 4 = 2024) \\ WW \ or \ WW = Week \ Code \ (01 \ to \ 53) \end{array}$

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Value	Unit
Continuous Drain-Source Voltage	VDS	60	V
Drain-Source Voltage for Short-Circuit Protection VIN = 5V	VDS(SC)	36	V
Drain-Source Voltage for Short-Circuit Protection VIN = 10V	VDS(SC)	20	V
Continuous Input Voltage	Vin	-0.2 to 10	V
Peak Input Voltage	Vin	-0.2 to 20	V
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Power Dissipation at $T_A = +25^{\circ}C$ (Note 5)	PD	1.5	W
Power Dissipation at $T_A = +25^{\circ}C$ (Note 6)	PD	0.6	W
Continuous Drain Current @ VIN = 10V; TA = +25°C (Note 5)	lo	1.3	А
Continuous Drain Current @ $V_{IN} = 5V$; $T_A = +25^{\circ}C$ (Note 5)	ID	1.1	А
Continuous Drain Current @ VIN = 5V; TA = +25°C (Note 6)	lD	0.7	А
Continuous Source Current (Body Diode) (Note 5)	ls	2.0	А
Pulsed Source Current (Body Diode) (Note 7)	ls	3.3	A
Unclamped Single Pulse Inductive Energy	EAS	550	mJ
Load Dump Protection	VLOAD_DUMP	80	V
Electrostatic Discharge (Human Body Model)	Vesd	4000	V
DIN Humidity Category, DIN 40 040	_	E	_
IEC Climatic Category, DIN IEC 68-1	_	40/150/56	—

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 5)	Reja	83	°C/W
Junction to Ambient (Note 7)	Reja	45	°C/W
Junction to Ambient (Note 6)	R _{θJA}	208	°C/W

5. For a device surface-mounted on 25mm x 25mm x 1.6mm FR-4 board with a high coverage of single sided 2oz weight copper. Allocation of 6cm² copper Notes: 33% to source tab and 66% to drain pin with source tab and drain pin electrically isolated. 6. For a device surface-mounted on FR-4 board with the minimum copper required for electrical connections. 7. For a device surface-mounted on FR-4 board as (a) and measured at t \leq 10s.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
Static Characteristics			•	•		<u>.</u>
Drain-Source Clamp Voltage	VDS(AZ)	60	70	75	V	I _D = 10mA
Off-State Drain Current	IDSS		0.1	3	μA	$V_{DS} = 12V, V_{IN} = 0V$
Off-State Drain Current	IDSS		3	15	μA	$V_{DS} = 32V, V_{IN} = 0V$
Input Threshold Voltage (Note 8)	Vin(th)	1	2.1	_	V	V _{DS} = V _{GS} , I _D = 1mA
Input Current	lin	_	0.7	1.2	mA	$V_{IN} = 5V$
Input Current	l _{IN}		1.5	2.7	mA	V _{IN} = 7V
Input Current	lin		4	7	mA	V _{IN} = 10V
Static Drain-Source On-State Resistance	RDS(ON)		520	675	mΩ	V _{IN} = 5V, I _D = 0.7A
Static Drain-Source On-State Resistance	R _{DS(ON)}		385	550	mΩ	$V_{IN} = 10V, I_D = 0.7A$
Current Limit (Note 9)	ID(LIM)	0.7	1.0	1.5	А	VIN = 5V, VDS > 5V
Current Limit (Note 9)	ID(LIM)	1	1.8	2.3	А	VIN = 10V, VDS > 5V
Dynamic Characteristics						•
Turn-On Time (V _{IN} to 90% I _D)	ton	_	3	_	μs	$R_L = 22\Omega$, $V_{IN} = 0V$ to $10V$ $V_{DD} = 12V$
Turn-Off Time (V _{IN} to 90% I_D)	tOFF	_	13	_	μs	$R_{L} = 22\Omega, V_{IN} = 10V \text{ to } 0V$ $V_{DD} = 12V$
Slew Rate On (70% to 50% VDD)	-dV _{DS} /dton	_	8	_	V/µs	$R_L = 22\Omega$, $V_{IN} = 0V$ to $10V$ $V_{DD} = 12V$
Slew Rate Off (50% to 70% V _{DD})	dV _{DS} /dt _{ON}	_	3.2	_	V/µs	$R_{L} = 22\Omega, V_{IN} = 10V \text{ to } 0V$ $V_{DD} = 12V$
Protection Functions (Note 10)			•	•		·
Minimum Input Voltage for Overtemperature Protection	Vprot	4.5	—	_	V	_
Thermal Overload Trip Temperature	TJT	+150	+175	_	°C	—
Thermal Hysteresis	—	_	+1	_	°C	—
Unclamped Single Pulse Inductive Energy TJ = +25°C	Eas	550	—	_	mJ	$I_{D(ISO)} = 0.7A, V_{DD} = 32V$
Unclamped Single Pulse Inductive Energy TJ = +150°C	E _{AS}	200	_	_	mJ	$I_{D(ISO)} = 0.7A, V_{DD} = 32V$
Inverse Diode						
Source-Drain Voltage	Vsd	_	_	1	V	$V_{IN} = 0V, -I_D = 1.4A$

Notes: 8. Protection features may operate outside spec for V_{IN} < 4.5V.

9. The drain current is limited to a reduced value when V_{DS} exceeds a safe level.
10. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the datasheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous, repetitive operation.



Application Information

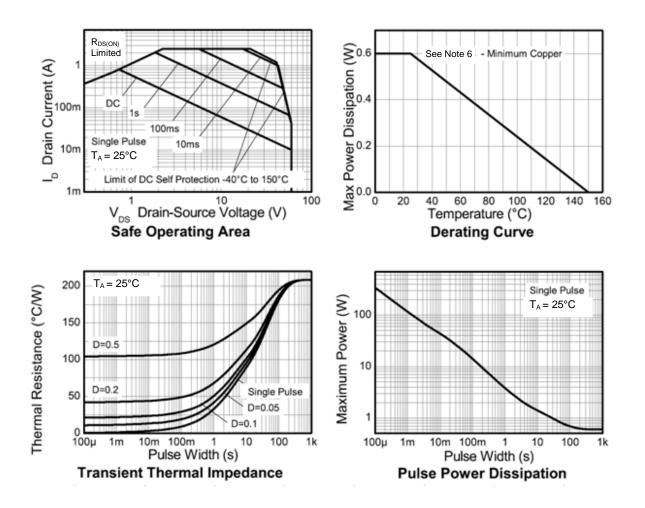
The current-limit protection circuitry is designed to de-activate at low V_{DS} to prevent the load current from being unnecessarily restricted during normal operation. The design max DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry (see *Typical Characteristics* graphs). This does not compromise the products ability to self-protect at low V_{DS}.

The overtemperature protection circuit trips at a minimum of +150°C. So the available package dissipation reduces as the maximum required ambient temperature increases. This leads to the following maximum recommended continuous operating currents.

Minimum Copper Area Characteristics

For minimum copper condition as described in Note 6.

May Ambient Temperature T	Maximum Continuous Current			
Max Ambient Temperature T _A	V _{IN} = 5V	V _{IN} = 10V		
+25°C at V _{IN} = 5V	720mA	840mA		
+70°C at V _{IN} = 5V	575mA	670mA		
+85°C at V _{IN} = 5V	520mA	605mA		
+125°C at V _{IN} = 5V	320mA	375mA		

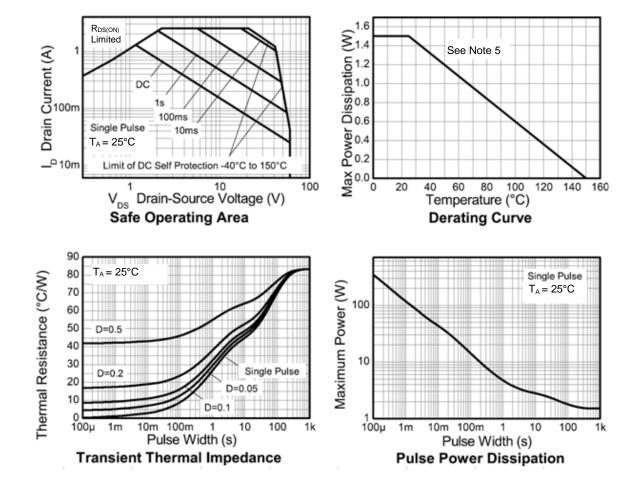




Large Copper Area Characteristics

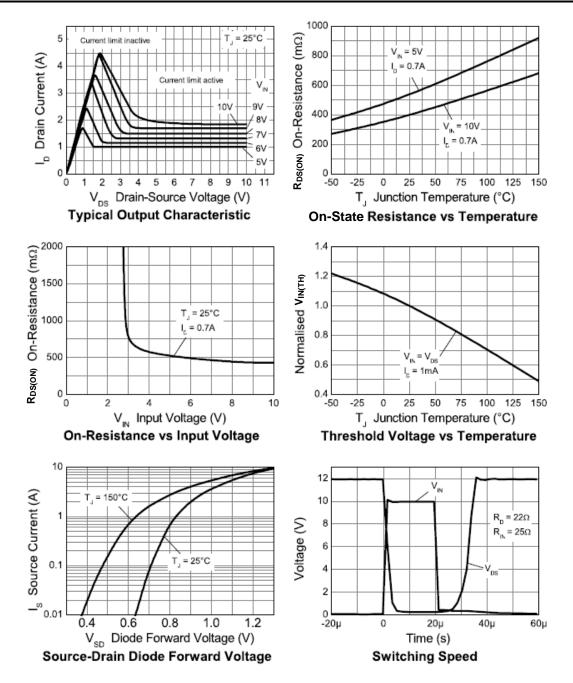
For large copper area as described in Note 5.

Max Ambient Temperature T.	Maximum Continuous Current			
Max Ambient Temperature T _A	V _{IN} = 5V	V _{IN} = 10V		
+25°C at V _{IN} = 5V	1140mA	1325mA		
+70°C at V _{IN} = 5V	915mA	1060mA		
+85°C at V _{IN} = 5V	825mA	955mA		
+125°C at V _{IN} = 5V	510mA	590mA		





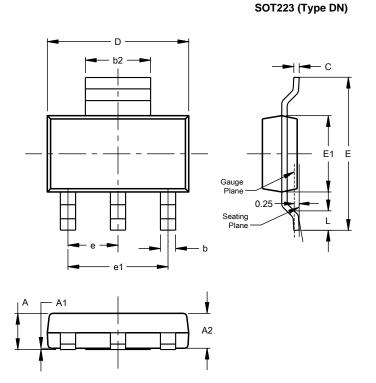
Typical Characteristics





Package Outline Dimensions

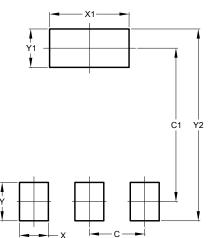
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
c	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
e			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type DN)	

Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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